

November 1994

LM748 Operational Amplifier

General Description

The LM748 is a general purpose operational amplifier with external frequency compensation.

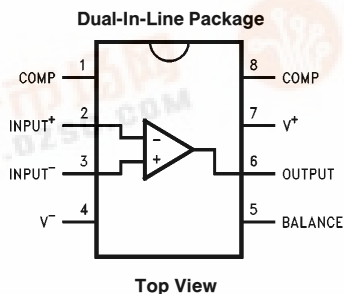
The unity-gain compensation specified makes the circuit stable for all feedback configurations, even with capacitive loads. It is possible to optimize compensation for best high frequency performance at any gain. As a comparator, the output can be clamped at any desired level to make it compatible with logic circuits.

The LM748C is specified for operation over the 0°C to +70°C temperature range.

Features

- Frequency compensation with a single 30 pF capacitor
- Operation from $\pm 5\text{V}$ to $\pm 20\text{V}$
- Continuous short-circuit protection
- Operation as a comparator with differential inputs as high as $\pm 30\text{V}$
- No latch-up when common mode range is exceeded
- Same pin configuration as the LM101

Connection Diagram



TL/H/11478-2

Order Number LM748CN
See NS Package Number N08B

LM748 Operational Amplifier



Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	$\pm 22\text{V}$
Power Dissipation (Note 1)	500 mW
Differential Input Voltage	$\pm 30\text{V}$

Input Voltage (Note 2)	$\pm 15\text{V}$
Output Short-Circuit Duration (Note 3)	
Operating Temperature Range:	
LM748C	$0^{\circ}\text{C to } +70^{\circ}\text{C}$
Storage Temperature Range	$-65^{\circ}\text{C to } +150^{\circ}\text{C}$
Lead Temperature (Soldering, 10 sec.)	$+300^{\circ}\text{C}$

Electrical Characteristics (Note 4)

Parameter	Conditions	Min	Typ	Max	Units
Input Offset Voltage	$T_A = 25^{\circ}\text{C}, R_S \leq 10\text{ k}\Omega$		1.0	5.0	mV
Input Offset Current	$T_A = 25^{\circ}\text{C}$		40	200	nA
Input Bias Current	$T_A = 25^{\circ}\text{C}$		120	500	nA
Input Resistance	$T_A = 25^{\circ}\text{C}$	300	800		k Ω
Supply Current	$T_A = 25^{\circ}\text{C}, V_S = \pm 15\text{V}$		1.8	2.8	mA
Large Signal Voltage Gain	$T_A = 25^{\circ}\text{C}, V_S = \pm 15\text{V}$ $V_{OUT} = \pm 10\text{V}, R_L \geq 2\text{ k}\Omega$	50	160		V/mV
Input Offset Voltage	$R_S \leq 10\text{ k}\Omega$			6.0	mV
Average Temperature Coefficient of Input Offset Voltage	$R_S \leq 50\Omega$		3.0		$\mu\text{V}/^{\circ}\text{C}$
	$R_S \leq 10\text{ k}\Omega$		6.0		$\mu\text{V}/^{\circ}\text{C}$
Input Offset Current	$T_A = 0^{\circ}\text{C to } +70^{\circ}\text{C}$			300	nA
	$T_A = -55^{\circ}\text{C to } +125^{\circ}\text{C}$			500	nA
Input Bias Current	$T_A = 0^{\circ}\text{C to } +70^{\circ}\text{C}$			0.8	μA
	$T_A = -55^{\circ}\text{C to } +125^{\circ}\text{C}$			1.5	μA
Supply Current	$T_A = +125^{\circ}\text{C}, V_S = \pm 15\text{V}$		1.2	2.25	mA
	$T_A = -55^{\circ}\text{C to } +125^{\circ}\text{C}$		1.9	3.3	mA
Large Signal Voltage Gain	$V_S = \pm 15\text{V}, V_{OUT} = \pm 10\text{V}$ $R_L \geq 2\text{ k}\Omega$	25			V/mV
Output Voltage Swing	$V_S = \pm 15\text{V}, R_L = 10\text{ k}\Omega$	± 12	± 14		V
	$V_S = \pm 15\text{V}, R_L = 2\text{ k}\Omega$	± 10	± 13		V
Input Voltage Range	$V_S = \pm 15\text{V}$	± 12			V
Common-Mode Rejection Ratio	$R_S \leq 10\text{ k}\Omega$	70	90		dB
Supply Voltage Rejection Ratio	$R_S \leq 10\text{ k}\Omega$	77	90		dB

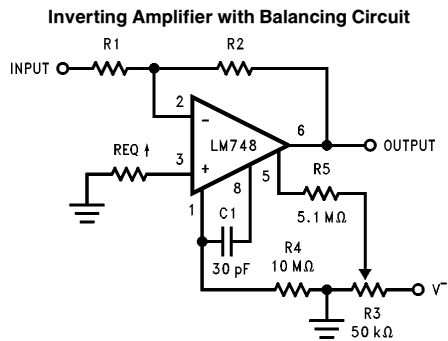
Note 1: For operating at elevated temperatures, the device must be derated based on a maximum junction to case thermal resistance of 45°C per watt, or 150°C per watt junction to ambient. (See Curves).

Note 2: For supply voltages less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

Note 3: Continuous short circuit is allowed for case temperatures to $+125^{\circ}\text{C}$ and ambient temperatures to $+70^{\circ}\text{C}$.

Note 4: These specifications apply for $\pm 5\text{V} \leq V_S \leq +15\text{V}$ and $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$, unless otherwise specified.

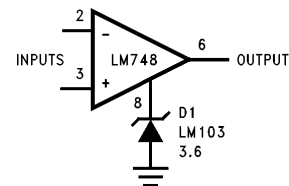
Typical Applications



†May be zero or equal to parallel combination of R1 and R2 for minimum offset.

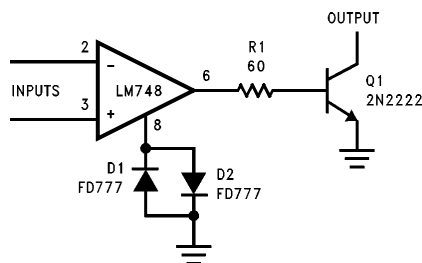
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Voltage Comparator for Driving DTL or TTL Integrated Circuits



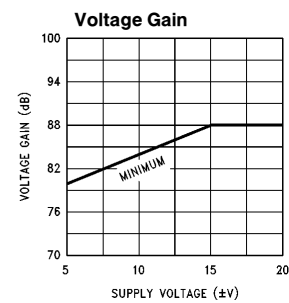
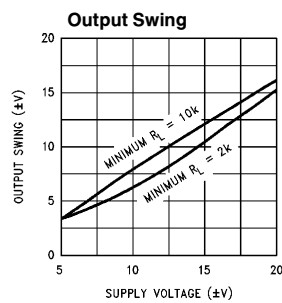
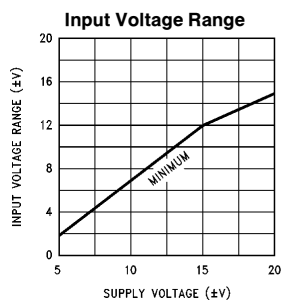
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Voltage Comparator for Driving RTL Logic or High Current Driver



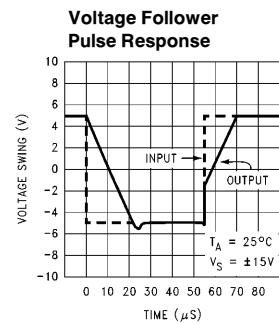
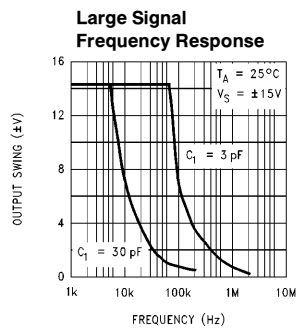
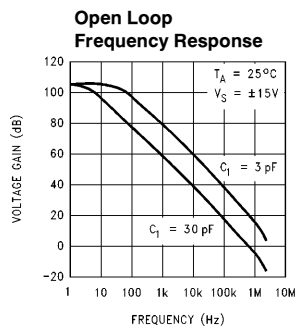
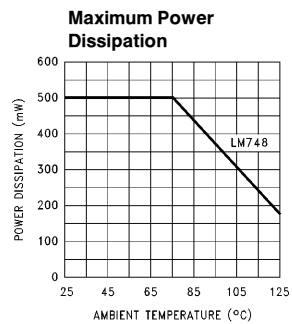
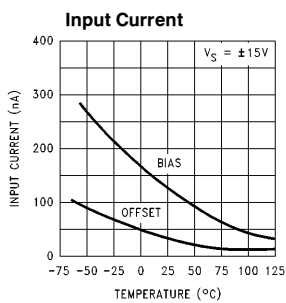
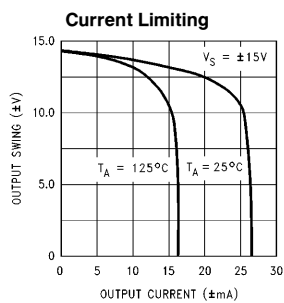
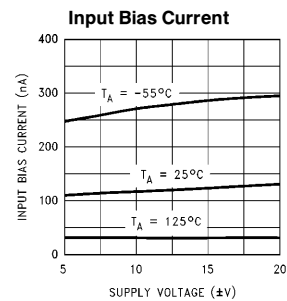
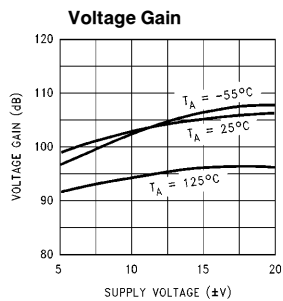
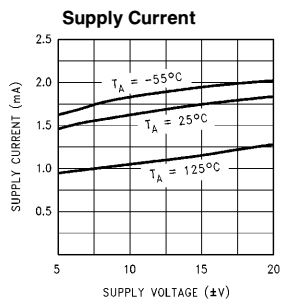
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Guaranteed Performance Characteristics (Note 4)

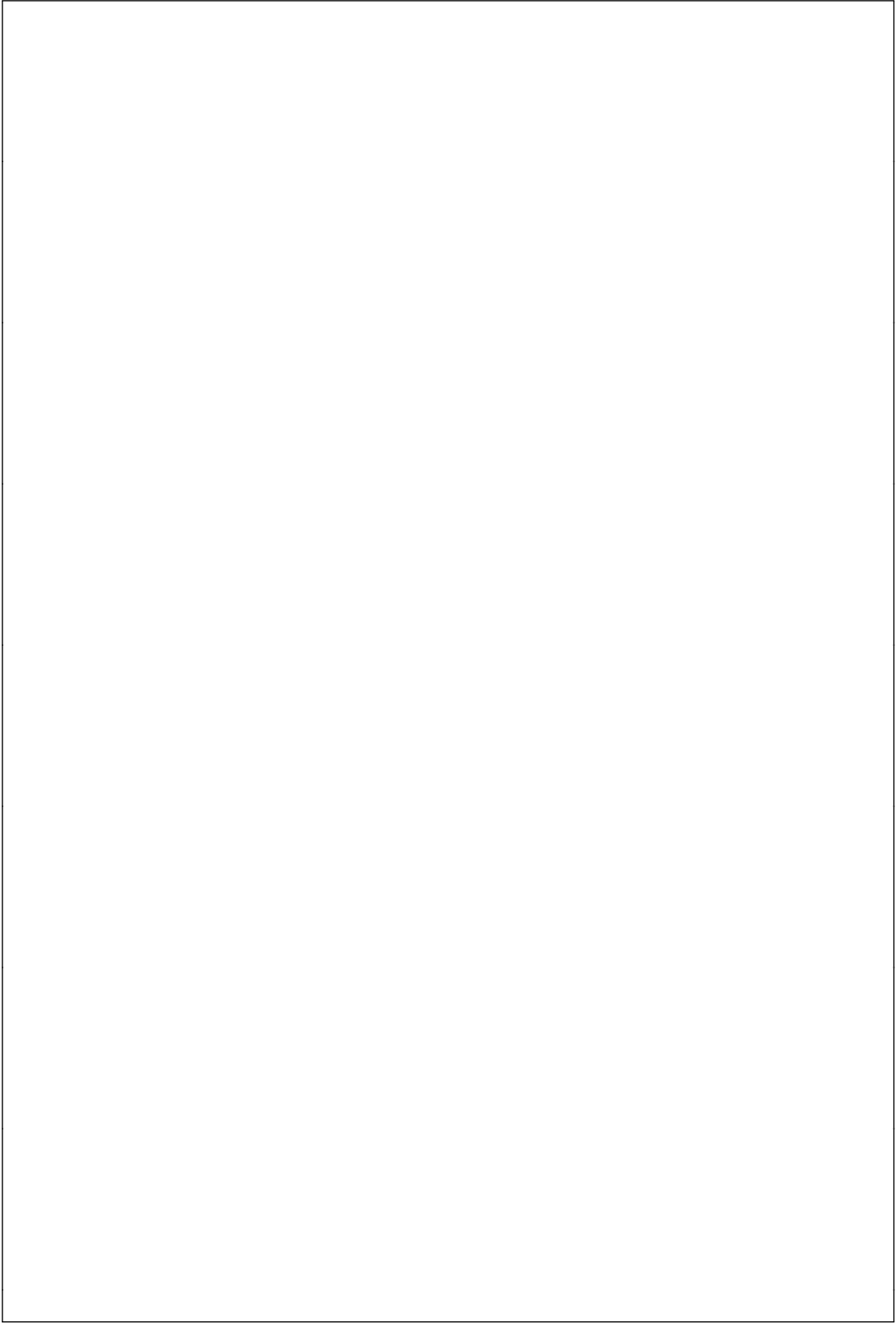


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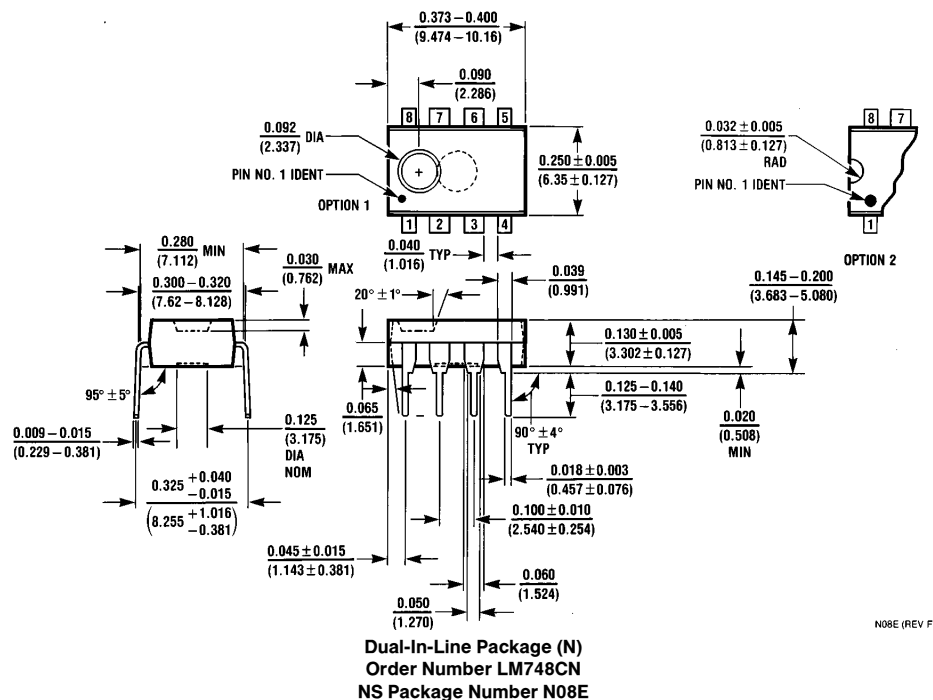
Typical Performance Characteristics



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Physical Dimensions inches (millimeters)



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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